	CY74FCT22 8-BIT BUFFER/LINE DRI WITH 3-STATE OUTP SCCS074-OCTOBER
Function and Pinout Compatible With FCT and F Logic	Q OR SO PACKAGE (TOP VIEW)
25- Ω Output Series Resistors Reduce Transmission-Line Reflection Noise	$ \overline{OE}_{A} \begin{bmatrix} 1 & 20 \end{bmatrix} V_{CC} \\ DA_{0} \begin{bmatrix} 2 & 19 \end{bmatrix} \overline{OE}_{B} $
TTL-Output-Level Version of Equivalent FCT Functions	$OB_0 \begin{bmatrix} 3 & 18 \end{bmatrix} OA_0$ $DA_1 \begin{bmatrix} 4 & 17 \end{bmatrix} DB_0$
Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics	OB ₁ [5 16] OA ₁ DA ₂ [6 15] DB ₁ OB ₂ [7 14] OA ₂
I _{off} Supports Partial-Power-Down Mode Operation	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$

- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Fully Compatible With TTL Input and Output Logic Levels
- 12-mA Output Sink Current
 15-mA Output Source Current
- 3-State Outputs

description

The CY74FCT2244T is an octal buffer and line driver that includes on-chip 25- Ω terminating resistors at each of the outputs to minimize noise resulting from reflections or standing waves in high-performance applications. The on-chip resistors reduce overall board space and component count. Designed to be employed as a memory address driver, clock driver, and bus-oriented transmitter/receiver, this device provides speed and drive capabilities commensurate with its fastest bipolar logic counterparts, while reducing power dissipation. The input and output voltage levels allow direct interface with TTL, NMOS, and CMOS devices, without the need for external components.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

		ONDENING		ATION	
Τ _Α	PAC	KAGET	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	4.3	CY74FCT2244CTQCT	FCT2244C
	SOIC - SO	Tube	4.3	CY74FCT2244CTSOC	FCT2244C
	3010 - 30	Tape and reel	4.3	CY74FCT2244CTSOCT	FC12244C
	QSOP – Q	Tape and reel	4.6	CY74FCT2244ATQCT	FCT2244A
–40°C to 85°C	SOIC - SO	Tube	4.6	CY74FCT2244ATSOC	FCT2244A
	3010 - 30	Tape and reel	4.6	CY74FCT2244ATSOCT	FC12244A
	QSOP – Q	Tape and reel	6.5	CY74FCT2244TQCT	FCT2244
	SOIC – SO	Tube	6.5	CY74FCT2244TSOC	FCT2244
	3010 - 30	Tape and reel	6.5	CY74FCT2244TSOCT	

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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 DB_3

GND 🛛 10

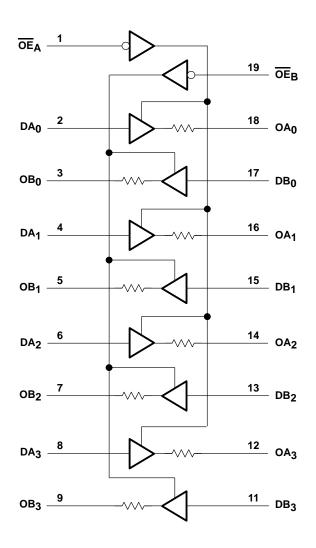
CY74FCT2244T 8-BIT BUFFER/LINE DRIVER WITH 3-STATE OUTPUTS SCCS074 - OCTOBER 2001

FUNCTION TABLE

	INPUTS	OUTPUT	
OEA	OEB	D	0
L	L	L	L
L	L	Н	н
Н	Н	Х	Z

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance (off) state

logic diagram





CY74FCT2244T **8-BIT BUFFER/LINE DRIVER** WITH 3-STATE OUTPUTS

SCCS074 - OCTOBER 2001

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range to ground potential	0.5	V to 7 V
DC input voltage range	0.5	V to 7 V
DC output voltage range	0.5	V to 7 V
DC output current (maximum sink current/pin)		120 mA
Package thermal impedance, θ_{JA} (see Note 1): Q package		68°C/W
SO package		58°C/W
Ambient temperature range with power applied, T _A	–65°C to	+135°C
Storage temperature range, T _{stg}	–65°C to	+150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ЮН	High-level output current			-15	mA
IOL	Low-level output current			12	mA
Т _А	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



CY74FCT2244T 8-BIT BUFFER/LINE DRIVER WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	5	MIN	TYP†	MAX	UNI
VIK	V _{CC} = 4.75 V,	I _{IN} = -18 mA			-0.7	-1.2	V
VOH	V _{CC} = 4.75 V,	I _{OH} = –15 mA		2.4	3.3		V
V _{OL}	V _{CC} = 4.75 V,	I _{OL} = 12 mA			0.3	0.55	V
ROUT	V _{CC} = 4.75 V,	I _{OL} = 12 mA		20	25	40	Ω
V _{hys}	All inputs				0.2		V
li li	V _{CC} = 5.25 V,	V _{IN} = V _{CC}				5	μA
IIН	V _{CC} = 5.25 V,	V _{IN} = 2.7 V				±1	μA
١	V _{CC} = 5.25 V,	V _{IN} = 0.5 V				±1	μA
IOZH	V _{CC} = 5.25 V,	V _{OUT} = 2.7 V				10	μA
IOZL	V _{CC} = 5.25 V,	V _{OUT} = 0.5 V				-10	μA
los‡	V _{CC} = 5.25 V,	VOUT = 0 V		-60	-120	-225	mA
l _{off}	$V_{CC} = 0 V,$	V _{OUT} = 4.5 V				±1	μA
ICC	V _{CC} = 5.25 V,	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 V$		0.1	0.2	mA
∆ICC	V _{CC} = 5.25 V, V _{IN} = 3	.4 V§, $f_1 = 0$, Outputs op	en		0.5	2	mA
ICCD [¶]		but switching at 50% duty $IN \le 0.2 \text{ V or } V_{IN} \ge V_{CC}$			0.06	0.12	mA MH
		One bit switching at f ₁ = 10 MHz	$V_{IN} \leq 0.2 \text{ V or} \\ V_{IN} \geq V_{CC} - 0.2 \text{ V}$		0.7	1.4	
1-#	$V_{CC} = 5.25 V,$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1	2.4	mA
I_C [#] Outputs open, $\overline{OE}_A = \overline{OE}_B = GND$	Eight bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.3	2.6	111/-	
		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		3.3	10.6ll	
Ci					5	10	pF
Co					9	12	pF

[†] Typical values are at $V_{CC} = 5 V$, $T_A = 25^{\circ}C$.

[‡]Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

§ Per TTL-driven input (VIN = 3.4 V); all other inputs at VCC or GND

This parameter is derived for use in total power-supply calculations.

[#]ΙC $= I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$

Where:

= Total supply current IC.

ICC = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input (VIN = 3.4 V)

D_H = Duty cycle for TTL inputs high

NΤ = Number of TTL inputs at DH

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

= Clock frequency for registered devices, otherwise zero fo

f₁ = Input signal frequency

= Number of inputs changing at f1 N₁

All currents are in milliamperes and all frequencies are in megahertz.

I Values for these conditions are examples of the I_{CC} formula.



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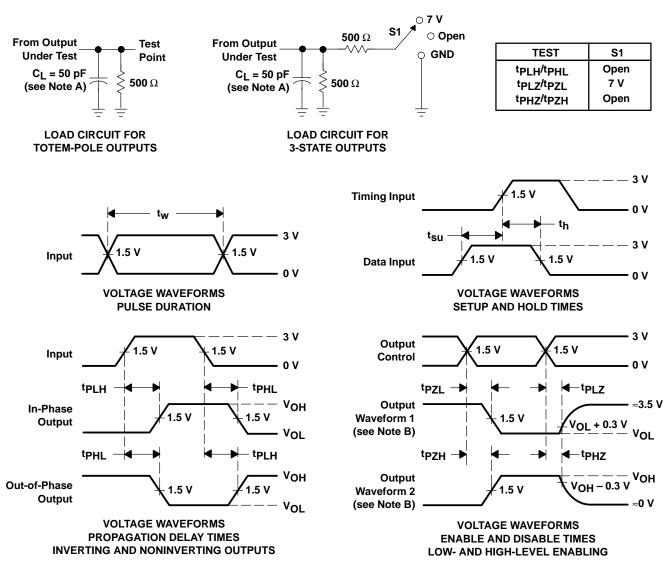
_			_		_				
PARAMETER	FROM	то	CY74FC	CY74FCT2244T		CY74FCT2244AT		CY74FCT2244CT	
	(INPUT)	(OUTPUT)	MIN	MIN MAX		MAX	MIN	MAX	UNIT
^t PLH	D	о	1.5	6.5	1.5	4.6	1.5	4.1	20
^t PHL	U	0	1.5	6.5	1.5	4.6	1.5	4.1	ns
^t PZH	OE	0	1.5	8	1.5	6.2	1.5	5.8	20
^t PZL	ÛE	0	1.5	8	1.5	6.2	1.5	5.8	ns
^t PHZ		0	1.5	7	1.5	5.6	1.5	5.2	ns
^t PLZ	UE		1.5	7	1.5	5.6	1.5	5.2	115

switching characteristics over operating free-air temperature range (see Figure 1)



CY74FCT2244T **8-BIT BUFFER/LINE DRIVER** WITH 3-STATE OUTPUTS

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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C_I includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control. C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
CY74FCT2244ATQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2244A	Samples
CY74FCT2244ATSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2244A	Samples
CY74FCT2244CTQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2244C	Samples
CY74FCT2244CTSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2244C	Samples
CY74FCT2244TQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2244	Samples
CY74FCT2244TSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2244	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



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STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT2244ATQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2244CTQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2244TQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1



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PACKAGE MATERIALS INFORMATION

16-Mar-2023



*All dimensions are nominal

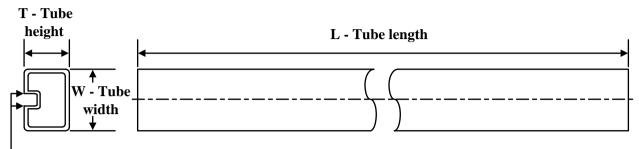
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT2244ATQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0
CY74FCT2244CTQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0
CY74FCT2244TQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0

TEXAS INSTRUMENTS

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TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CY74FCT2244ATSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2244CTSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2244TSOC	DW	SOIC	20	25	507	12.83	5080	6.6

DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AD.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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